

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Patent No. ....7,192,829 B2  
Patent Issue Date ..... March 20, 2007  
Application Serial No. .... 09/118,359  
Filing Date ..... July 17, 1998  
Assignee ..... Micron Technology, Inc.  
Inventorship ..... J. Dennis Keller et al.  
Attorney's Docket No. ....MI22-587  
Title: ..... Methods of Forming Floating Gate Transistors

**REQUEST FOR CERTIFICATE OF CORRECTION OF PATENT**  
**FOR PTO MISTAKE (37 C.F.R. 1.322(a))**

To: Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450  
ATTN: Decision and Certificate of Correction  
Branch of the Patent Issue Division  
  
From: Robert C. Hyta (Tel. 509-624-4276; Fax 509-838-3424)  
Wells St. John P.S.  
601 W. First Avenue, Suite 1300  
Spokane, WA 99201-3828

Sir:

It is hereby requested that a Certificate of Correction be issued with respect to Patent No. 7,192,829 B2, granted March 20, 2007, in accordance with the Certificate of Correction form attached hereto.

The error listed on the Certificate of Correction form was apparently incurred through the fault of the PTO as will be disclosed by the records of files in the Office.

Since this Certificate of Correction is being requested due to a PTO error, it is believed that no fee is due. However, in the event that a fee is required for issuance of this Certificate of Correction, please charge the fee specified under

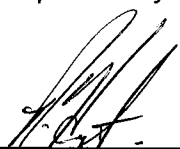
37 C.F.R. § 1.20(a) to Deposit Account No. 23-0925. Please credit Deposit Account No. 23-0925 with any overpayment of the above fee.

Attached hereto is Form PTO-1050, with the Form being suitable for printing.

Respectfully submitted,

Dated: 8/16/07

By: \_\_\_\_\_

  
Robert C. Hyta  
Reg. No. 46,791

UNITED STATES PATENT AND TRADEMARK OFFICE  
**CERTIFICATE OF CORRECTION**

PATENT NO. : US 7,192,829 B2  
ISSUED : March 20, 2007  
APPLICATION NO.: 09/118,359  
INVENTORS : J. Dennis Keller et al.

It is certified that an error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Col. 3, line 1 –

Replace “50-100 nm, or greater than about grain boundaries in an”  
With --50-100 nm, or greater than about 25 grain boundaries in an--

Page  
1 of 1

**Mailing Address of Sender:**

Robert C. Hyta  
Wells St. John P.S.  
601 West First Avenue, Suite 1300  
Spokane, WA 99201-3828

U.S. Patent No.: 7,192,829 B2